

Differences in FM25L256B and FM25V02

Applies to 256Kb SPI F-RAM Devices



DESCRIPTION

This document points out the differences the FM25L256B and FM25V02 F-RAM devices. For most designs, the FM25V02 device can be considered a superset of the FM25L256B. The two devices are identical in terms of pinout, package dimensions and composition, and read/write functionality. In terms of speed, both operate up to 20MHz but the FM25V02 allows read/write operations up to 40MHz. It also adds a sleep mode feature which effectively lowers the standby/idle current to 8 μ A.

DROP-IN REPLACEMENT OR NOT

From a software point of view, the two devices are identical. From a hardware point of view, the key difference between the two devices is the FM25V02's higher standby current. The FM25V02 adds many features: operates to down to 2.0V, sleep mode capability, Device ID feature, and higher speed capability. The summary table below highlights the differences.

COMPATIBILITY CHART

FM25L256B Feature or Spec		... is FM25V02 compatible?
Package		Yes (SOIC)
Pinout		Yes
Temperature Range		Yes
Operating Voltage		Yes
Operating Current		Yes
Standby Current		No
R/W Function		Yes
Timing/Freq		Yes
Data Retention		Yes
Endurance		Yes

DETAILED COMPARISON TABLE

Differences are highlighted in yellow.

	FM25L256B	FM25V02	Comments
Package Types	-G, -DG	-G	SOIC only
Package Outlines	SOIC-8, TDFN-8	SOIC-8	Same SOIC outline and board footprint
Pinout	-	-	Same
Temperature Range	-40C to +85C	-40C to +85C	Same
Operating Voltage Range	2.7 to 3.6V	2.0 to 3.6V	FM25V02 allows operation down to 2V
Active Supply Current	500 μ A @ 1MHz 10.0mA @ 20MHz	300 μ A @ 1MHz 3.0mA @ 40MHz	The 25V02 offers lower active current even at low freq.
Standby Current	10 μ A	150 μ A	FM25V02 has higher I_{SB} .
Sleep Mode Current	-	8 μ A	FM25V02 offers a sleep mode which reduces the "idle" current
Read/Write Function	-	-	Same 2-byte addressing, same op-codes
Clock Freq	20 MHz	40 MHz	FM25V02 offers higher speed
Data Retention	10 yrs	10 yrs	Same
Endurance	Unlimited	1E+14	FM25V02 is unlimited at 20MHz (85 yrs for a 64-byte loop)
OTHER			
V_{DD} Rise/Fall Time	50 μ s/V, 100 μ s/V	50 μ s/V, 100 μ s/V	Same
t_{PU} Power Up Time	10 ms	0.25 ms	FM25V02 faster to first access
/HOLD pin pullup	-	Internal pullup	Most systems tie /HOLD to V _{DD} but this should be checked in your design.
Device ID Feature	-	Yes	